

### General Description

The SY5055 is a PFC+LLC combo controller, which integrates a Boost PFC controller and a resonant half-bridge controller.

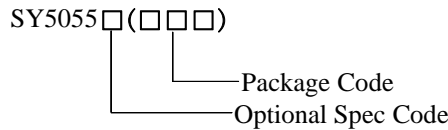
The Boost converter works in CrM/DCM mode to minimize switching losses and get better EMI performance. Proprietary control is adopted to get unity PF and lowest THD. Burst function increases efficiency at low load. Reliable input BO/BI protection, Boost output OVP/UVP, over current protection, Boost feedback protection guarantees safety work.

The LLC converter with proprietary control achieves fast dynamic response and easy loop compensation parameters design. The peripheral devices count is greatly reduced to save BOM cost. The SY5055 also has Output OVP, OTP and OLP for safety operation.

### Features

- PF>0.95, THD<5%
- Boost Quasi Resonant (QR) Operation
- Boost Burst Operation at Light Load
- LLC Fast Dynamic Response
- LLC Integrated Half-bridge Driver
- Input BO/BI Protection
- Boost Output, LLC Output OVP
- Cycle by Cycle Peak Current Protection
- Over Temperature Protection
- LLC Capacitive Mode Protection

### Ordering Information

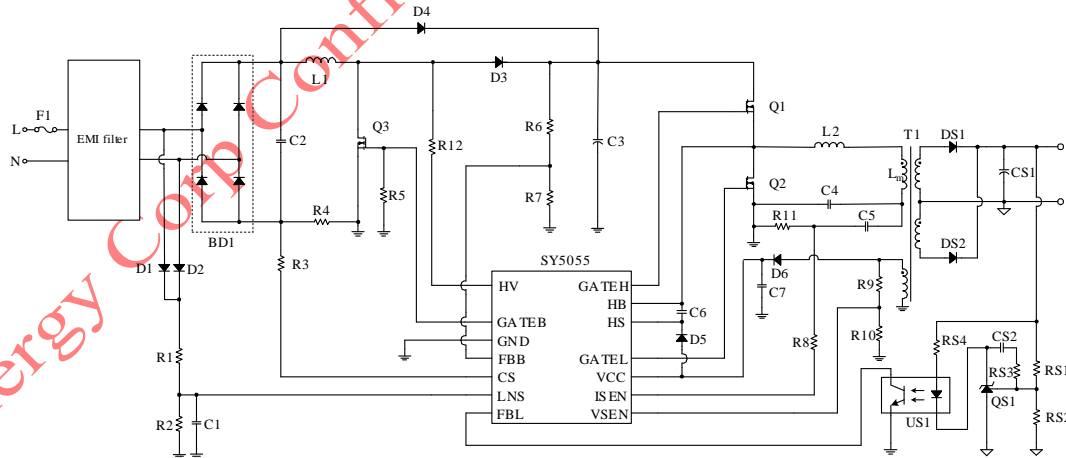


Ordering Number	Package type	Note
SY5055FFP	SOP16	----

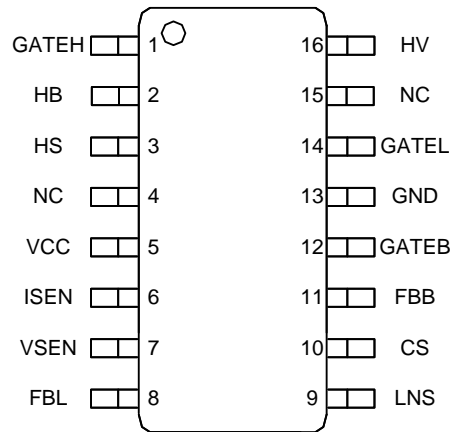
### Applications

- LCD Television
- Desktop, All in One PC
- Adapter, Charger
- Printer

### Typical Applications

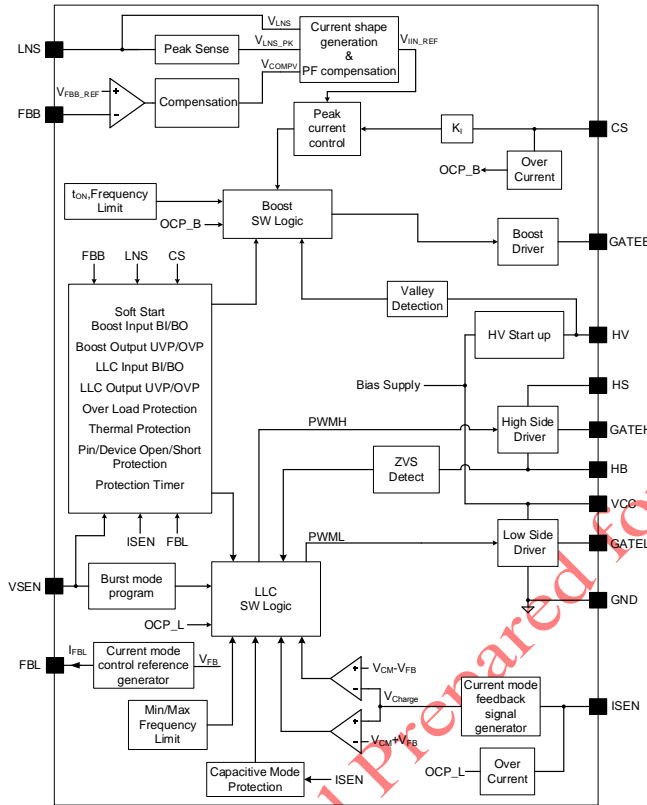


Typical Applications

**Pinout** (top view)

**SOP16**
**Top Mark: EYFxyz** (device code: EYF, *x*=year code, *y*=week code, *z*=lot number code)

Pin number	Pin Name	Pin Description
1	GATEH	Half bridge controller high side drive pin.
2	HB	Half bridge controller high side ground pin.
3	HS	Half bridge controller high side bias supply pin.
4	NC	Not connected.
5	VCC	Bias supply pin.
6	ISEN	Half bridge controller resonant current sense pin.
7	VSEN	Half bridge controller output voltage sense pin.
8	FBL	Half bridge controller control input pin.
9	LNS	PFC controller input voltage sense pin.
10	CS	PFC controller input current sense pin.
11	FBB	PFC controller output feedback pin.
12	GATEB	PFC controller gate drive pin.
13	GND	Ground pin.
14	GATEL	Half bridge controller low side drive pin.
15	NC	Not connected.
16	HV	HV start-up pin.

**Block Diagram**



**Block Diagram**

**Absolute Maximum Ratings** (Note 1)

HV	-----	-0.3V ~ 650V
HB	-----	-3V ~ 650V
HS	-----	HB-0.3V ~ HB+30V
GATEH	-----	HB-0.3V ~ HB+15V
VCC	-----	-0.3V ~ 30V
I <sub>CS</sub> (Note2)	-----	-10mA~+20mA
CS, ISEN	-----	-1.1V~+1.1V
FBB, LNS, FBL, VSEN	-----	-0.3V~3.6V
GATEB, GATEL	-----	-0.3V ~ 15V
Power Dissipation, @ T <sub>A</sub> = 25°C SOP16	-----	1.02W
Package Thermal Resistance (Note 3)		
SOP16, θ <sub>JA</sub>	-----	122°C/W
SOP16, θ <sub>JC</sub>	-----	11.5°C/W
Junction Temperature Range	-----	-45°C~150°C
Lead Temperature (Soldering, 10 sec.)	-----	260°C
Storage Temperature Range	-----	-65°C ~ 150°C

**Recommended Operating Conditions**

VCC	-----	10V~24V
HS-HB	-----	9V~24V
Junction Temperature Range	-----	-40°C ~ 125°C
Ambient Temperature Range	-----	-40°C ~ 105°C

## Electrical Characteristics

( $V_{VCC} = 15V$  (Note 4),  $T_A = 25^\circ C$  unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
<b>VCC Pin Section</b>						
VCC Turn-on Threshold	$V_{VCC\_ON}$	Voltage rising	23	24	25	V
VCC Turn-off Threshold	$V_{VCC\_OFF}$	Voltage falling	8.5	9	9.5	V
VCC Low for HV Start Threshold	$V_{VCC\_LO}$		8.9	9.5	10	V
VCC Short Circuit Protection	$V_{VCC\_SCP}$		0.6	0.8	1	V
VCC Shunt Voltage Protection	$V_{VCC\_Shunt}$		25.4	26.4	27.4	V
VCC OVP Threshold	$V_{VCC\_OVP}$		$V_{VCC\_Shunt} + 0.4$	$V_{VCC\_Shunt} + 0.75$	$V_{VCC\_Shunt} + 1.1$	V
VCC OVP Trigger Number of Switching Cycles	$N_{VCC\_OVP}$			4		
Quiescent Current	$I_Q$		1.3	1.6	1.9	mA
Standby Current	$I_{SDY}$		300	400	500	$\mu A$
Enable Off Current	$I_{ENOFF}$			200	280	$\mu A$
VCC Max Shunt Current	$I_{Shunt}$	$V_{VCC} > 26V$ (Note 5)	8	11	14.5	mA
VCC Fault Restart Timer	$T_{VCC\_timeout}$		0.69	1	1.1	s
<b>HV Pin Section</b>						
HV Start-up Current at VCC SCP	$I_{ST\_L}$	$V_{VCC} < 0.7V$	0.4	0.5	0.6	mA
HV Start-up Current at Normal State	$I_{ST\_N}$		5.2	6	7	mA
Maximum Charge Time	$T_{VCC\_charge}$		44	63	84	ms
Boost 2 <sup>nd</sup> OVP Threshold	$V_{HV\_OVPTH}$		480	505	530	V
HV OVP Number of Consecutive off Time for Trigger	$N_{HV\_OVP}$			4		
QR dV/dt Sense Threshold	$V_{HV\_TH}$	(Note 5)	24	40	56	V/ $\mu s$
QR Time Out Time	$T_{ZCS}$		2.2	3.3	4.4	$\mu s$
<b>FBB Pin Section</b>						
Boost Output Regulation Reference	$V_{FBB\_REF}$		1.18	1.2	1.22	V
Boost Output UVP Threshold	$V_{FBB\_UVP}$	16.7% of Boost $V_{out}$	170	200	230	mV
Boost Output OVP Threshold	$V_{FBB\_OVP}$	107.5% of Boost $V_{out}$	1.255	1.29	1.325	V
Boost & LLC Disable Threshold	$V_{FBB\_ENB}$		2.05	2.3	2.5	V
LLC Input BO Threshold	$V_{FBB\_BO}$		690	740	790	mV
LLC Input BI Threshold	$V_{FBB\_BI}$		900	940	980	mV
Pin Open Detection Source Current	$I_{FBB\_OPEN}$	For open pin	50	100	200	nA
<b>CS Pin Section</b>						
Boost Peak Current Limit	$V_{CS\_LIMIT}$		-740	-700	-660	mV

Inductor Saturation or Short-circuit Protection Limit	V <sub>LS_LIMIT</sub>		-900	-850	-800	mV
Inductor Saturation or Short-circuit Protection Trigger Number	N <sub>LStimer</sub>			4		
Boost Current Sense Resistor Short Circuit Protection Threshold	V <sub>CS_RSCP</sub>		-65	-50	-35	mV
Boost Current Sense Resistor Short Circuit Protection Timer	T <sub>CS_RSCP</sub>			4		μs
Voltage Threshold at Boost Over Power Protection	V <sub>COMPV_OPP</sub>			1.33		V
Calculate Coefficient of Boost Over Power Protection	K <sub>PFCOPP</sub>			0.073		
Boost over Power Protection Timer	T <sub>COMPV_OPP</sub>		180	256	290	ms
<b>LNS Pin Section</b>						
X-cap Maximum Discharge Time	T <sub>X_MAX</sub>		44	63	82	ms
X-cap Discharge Debounce Time	T <sub>XDIS_DBT</sub>		44	63	82	ms
Boost Input Brown Out Timer	T <sub>PROT_LNS_BO</sub>		44	63	82	ms
Boost Input Brown Out Threshold	V <sub>LNS_BO</sub>		374	395	425	mV
Boost Input Brown in Threshold	V <sub>LNS_BI</sub>		450	472	495	mV
Pin Open Detection Source Current	I <sub>LNS_OPEN</sub>		50	100	200	nA
<b>GATEB Pin Section</b>						
Drive Limit Voltage	V <sub>GATEB_DRV</sub>		10.1	10.9	11.6	V
Drive Voltage within T <sub>on,min,B</sub>	V <sub>GATEB_TH</sub>			8.5		V
Source Current	I <sub>SOURCE_GATEB</sub>	V <sub>GATEB</sub> =8.5V	400	600	800	mA
Sink Current	I <sub>SINK_GATEB</sub>	V <sub>GATEB</sub> =2V	0.3			A
		V <sub>GATEB</sub> =11V <sup>(Note 5)</sup>	1	1.4	1.8	A
Boost Minimum ON Time	T <sub>ON_MIN_B</sub>		200	300	400	ns
Boost Maximum ON Time	T <sub>ON_MAX_B</sub>		20	30	40	μs
Boost Minimum OFF Time	T <sub>OFF_MIN_B</sub>		0.7	1	1.5	μs
Boost Maximum OFF Time	T <sub>OFF_MAX_B</sub>		20	30	40	μs
Toffmax if CS<-850mV and within T <sub>LLC,delat</sub>	T <sub>offmax</sub>		70	100	130	μs
Boost Minimum Switching Period	T <sub>SW_MIN_B</sub>		2	2.9	4	μs
<b>FBL Pin Section</b>						
Open Loop Protection Threshold Current	I <sub>FBL_225%</sub>		12	23	33	μA

Open Loop Protection Trigger Time	T <sub>OLP</sub>		46	63	89	ms
Overpower Protection Trigger Time	T <sub>OPP</sub>		179	256	290	ms
Max off Time for DCM Mode	T <sub>offmax_DCM</sub>	R <sub>ISENSE</sub> + R <sub>ISEN</sub> =82Ω		1.67		μs
		R <sub>ISENSE</sub> + R <sub>ISEN</sub> =160Ω		2.5		μs
		R <sub>ISENSE</sub> + R <sub>ISEN</sub> =285Ω		3.3		μs
		R <sub>ISENSE</sub> + R <sub>ISEN</sub> =475Ω		5		μs
Regulated Burst Frequency for Burst Mode	F <sub>Burst</sub>		0.85	1	1.4	kHz
<b>ISEN Pin Section</b>						
Resonant Current Sample Resistor Calculate Coefficient	k	R <sub>ISENSE</sub> + R <sub>ISEN</sub> =82Ω		4.1 × 10 <sup>-7</sup>		
		R <sub>ISENSE</sub> + R <sub>ISEN</sub> =160Ω		6.15 × 10 <sup>-7</sup>		
		R <sub>ISENSE</sub> + R <sub>ISEN</sub> =285Ω		8.21 × 10 <sup>-7</sup>		
		R <sub>ISENSE</sub> + R <sub>ISEN</sub> =475Ω		1.23 × 10 <sup>-6</sup>		
LLC Current Sense Resistor Short Circuit Protection Threshold	V <sub>ISEN_RSCP</sub>		30	50	80	mV
LLC Current Sense Resistor Short Circuit Protection Timer	T <sub>ISEN_RSCP</sub>			4		μs
ISEN Max Current Limit	V <sub>ISEN_L</sub>	R <sub>GATEB</sub> =30kΩ	±600	±660	±720	mV
		R <sub>GATEB</sub> =18kΩ	±700	±760	±820	mV
		R <sub>GATEB</sub> =10kΩ	±8000	±860	±920	mV
ISEN Max Current Limit Protection Timer	T <sub>IL_protect</sub>		20	32	44	ms
<b>VSEN Pin Section</b>						
LLC Output OVP Counter	N <sub>OVP_COUNT</sub>			4		
LLC Output OVP Reference	V <sub>VSEN_OVP</sub>		1.42	1.47	1.54	V
LLC Disable Threshold	V <sub>VSEN_ENB</sub>		1.8	2.2	2.5	V
LLC Output UVP Reference	V <sub>VSEN_UVP</sub>		370	397	425	mV
LLC Output UVP Timer	T <sub>VSEN_UVP</sub>		22	32	44	ms
Pin Open Detection Source Current	I <sub>VSEN_OPEN</sub>		50	100	200	nA
<b>GATEL Pin Section</b>						
Drive Limit Voltage	V <sub>GATEL_DRV</sub>		10.5	11.5	12.5	V
Source Current	I <sub>SOURCE_GATEL</sub>	V <sub>GATEL</sub> =4V	200	350	500	mA
Sink Current	I <sub>SINK_GATEL</sub>	V <sub>GATEL</sub> =2V	0.3			A
		V <sub>GATEL</sub> =11V	1	1.4	1.8	A
LLC Minimum on Time	T <sub>ON_MIN_L</sub>		250	400	550	ns
LLC Maximum on Time	T <sub>ON_MAX_L</sub>		12	20	28	μs
Bootstrap Charge Time	T <sub>BST</sub>		3	5	7	μs
<b>HB Pin Section</b>						
dV/dt Threshold for HB ZVS	dV/dt <sub>ZVS</sub>	(Note 5)	52	80	108	V/μs
Minimum Dead Time for ZVS	T <sub>D_MIN</sub>		120	185	250	ns

Maximum Dead Time for ZVS	$T_{D\_MAX}$		0.8	1	1.2	$\mu s$
<b>HS Pin Section (Signal Refer to HB)</b>						
HS Turn-on Threshold	$V_{HS\_ON}$		6.5	7.5	8.5	V
HS Turn-off Threshold	$V_{HS\_OFF}$		5.8	6.4	7.1	V
HS Quiescent Current	$I_{Q\_HS}$		10	20	50	$\mu A$
<b>GATEH Pin Section (Signal Refer to HB)</b>						
Drive Limit Voltage	$V_{GATEH\_DRV}$		10.5	11.5	12.6	V
Source Current	$I_{SOURCE\_GATEH}$	$V_{GATEH}-V_{HB}=4V$	200	350	500	mA
Sink Current	$I_{SINK\_GATEH}$	$V_{GATEH}-V_{HB}=2V$	0.3			A
		$V_{GATEH}-V_{HB}=11V$	1	1.4	1.8	A
<b>Thermal Section</b>						
Thermal Shut Down Temperature	$T_{SD}$	(Note 5)		150		$^{\circ}C$
Thermal Shut Down Temperature Hysteresis	$T_{SD\_HSY}$	(Note 5)		20		$^{\circ}C$

Note 1: Stresses beyond the “Absolute Maximum Ratings” may cause permanent damage to the device. These are stress ratings only. Functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

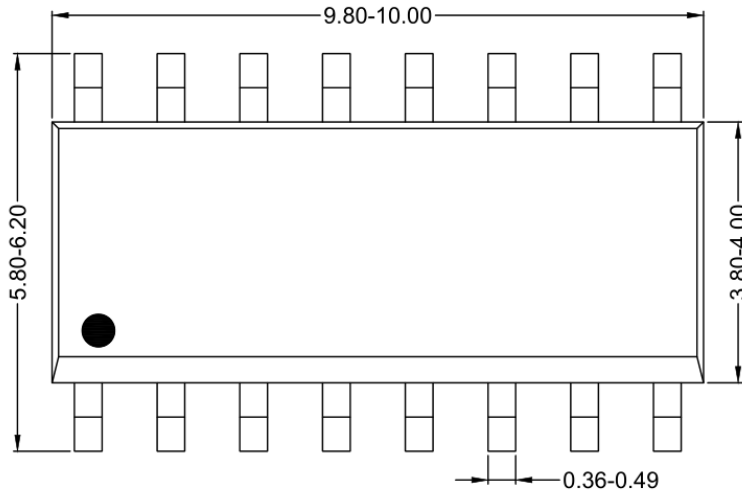
Note 2: The IC internal diode will clamp the voltage of CS pin. During the IC operating,  $I_{cs}$  should not exceed -10mA if  $V_{cs}$  reaches -1.1V.

Note 3:  $\theta_{JA}$  is measured in the natural convection at  $T_A = 25^{\circ}C$  on a low effective single layer thermal conductivity test board of JEDEC 51-3 thermal measurement standard.

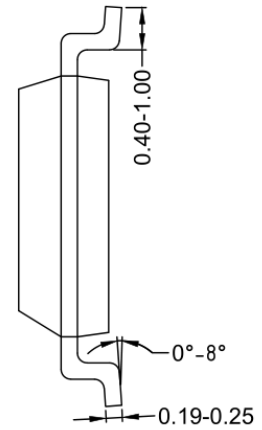
Note 4: Increase VCC pin voltage gradually higher than  $V_{VCC\_ON}$  voltage then turn down to 15V.

Note 5: Guaranteed by design.

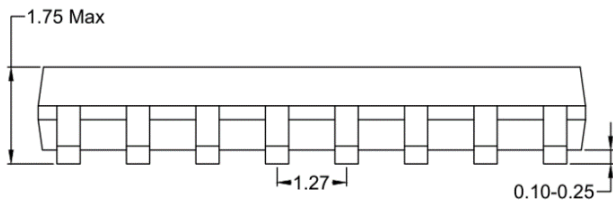
## SOP16 Package Outline & PCB Layout



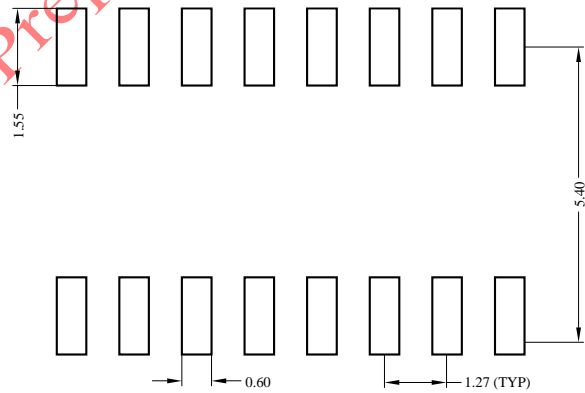
**Top View**



**Side View**



**Front View**



**Recommended PCB layout**

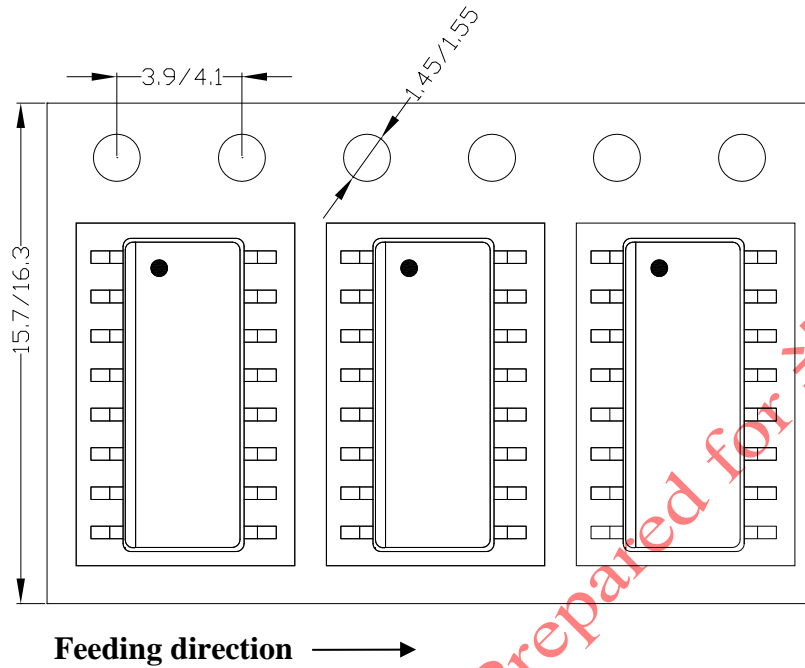
**Notes:** All dimension in millimeter and exclude mold flash & metal burr.



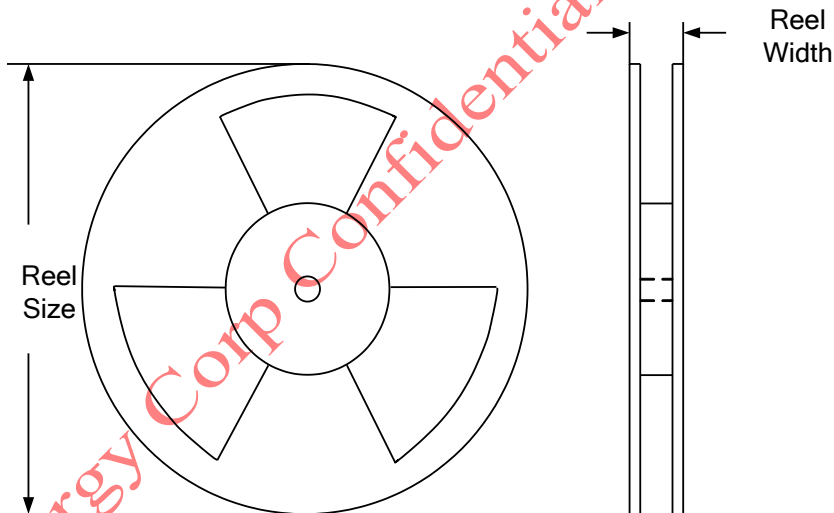
## Taping & Reel Specification

### 1. Taping orientation

SOP16



### 2. Carrier Tape & Reel specification for packages



Package types	Tape width (mm)	Pocket pitch(mm)	Reel size (Inch)	Reel width(mm)	Trailer length(mm)	Leader length (mm)	Qty per reel
SOP16	16	8	13"	12.4	400	400	2500

### 3. Others: NA